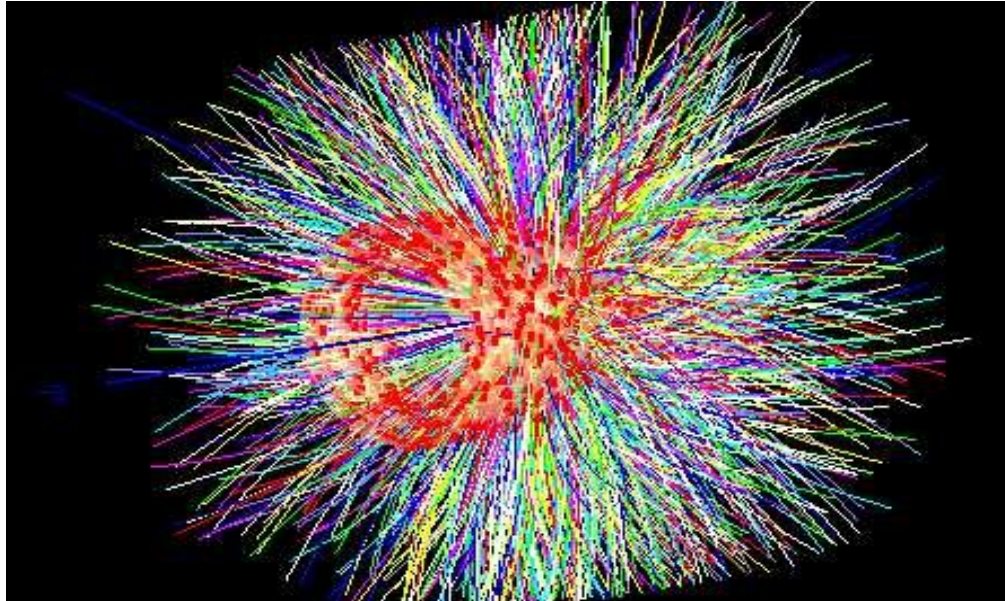


Upgrade of the ATLAS Silicon-Strip Detector for the High-Luminosity LHC



Conrad Friedrich, Ingo Bloch, Sebastian Gerhardt,
Tai-Hua Lin, Laura Rehnisch, Malik Aliev, Heiko Lacker,
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Deutsches Elektronen-Synchrotron DESY

Spring Block Course 2012 - March 13th 2012

> Upgrades towards the HL-LHC

- motivation & current LHC upgrade schedule
- requirements & challenges for Detectors at the HL-LHC

> Upgrade of the ATLAS Semiconductor Tracker (SCT)

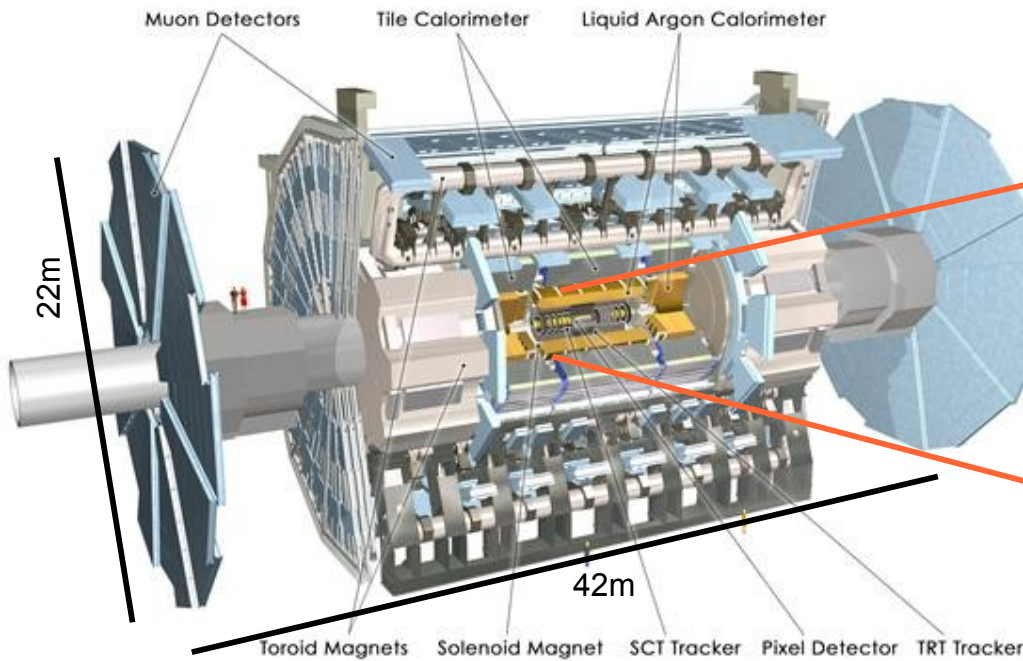
- Tracker upgrade: specs & baseline layout
- strip detector integration concepts (Staves, Supermodules, Petals)
- time-line & projects at DESY/HU

> Prototyping

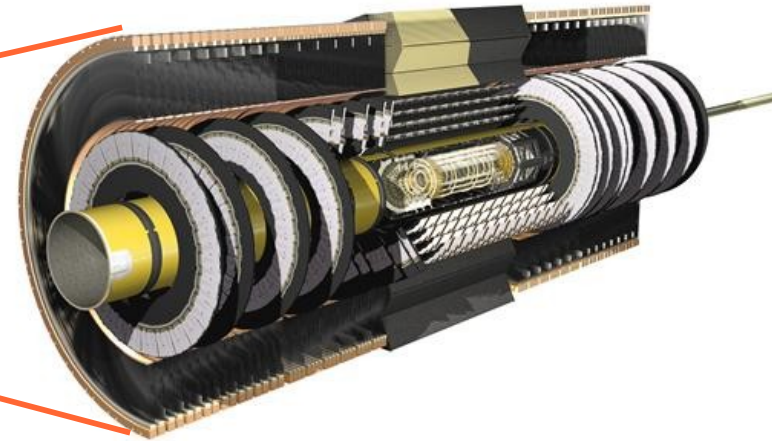
- construction of barrel module prototypes
- data acquisition & electrical testing

> Summary & Outlook

ATLAS & Inner Detector



ATLAS Inner Detector



- Inner Detector consists of 3 sub-detectors embedded in a 2T axial field
- Silicon Pixel Detector
 - 3 layers & 3 wheels - 1744 modules w. $50 \times 400 \mu\text{m}^2$ pixels
- Silicon Strip Detector (SCT)
 - 4 layers & 9 wheels - 4088 modules w. 12.6 cm long strips
- Transition Radiation Tracker (TRT) - 370.000 straws - 144 cm long drift tubes

high luminosity LHC (HL-LHC): motivation & physics goals

- **HL-LHC in short: increase recorded luminosity by a factor of 10**
 - improve precision in measurements within Standard Model & beyond
 - enlarge discovery reach in high-mass region
- **many studies require tracking performance to be kept at present value**

→ **Upgrade of detectors indispensable**

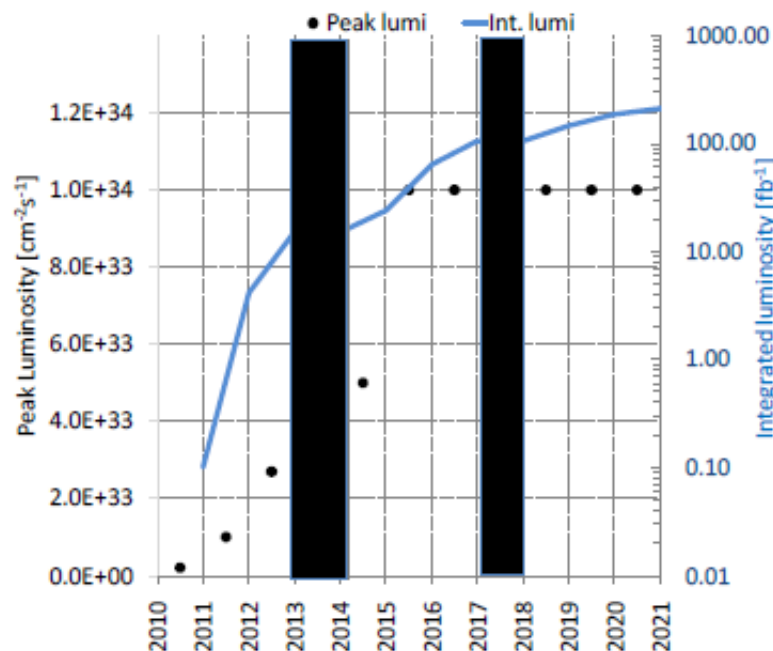
- **HL-LHC goals & target specifications:**

- peak luminosity: $5 \times 10^{34} \text{ cm}^{-2} \text{ s}^{-1}$
- integrated luminosity: $\sim 250 \text{ fb}^{-1}$ per year
- record $\sim 3000 \text{ fb}^{-1}$ in approx. 12 years

Phase 0 – 2014 (followed by 14 TeV running)

Phase 1 – 2018 ($\sim 200\text{-}300 \text{ fb}^{-1}$ until Phase 2 shutdown)

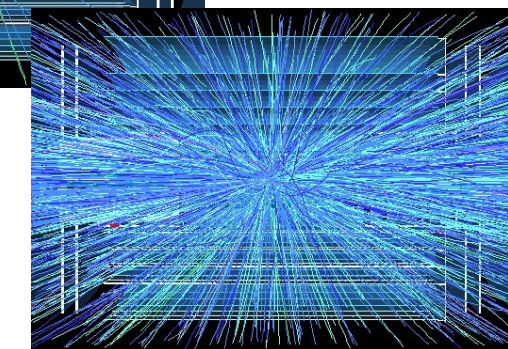
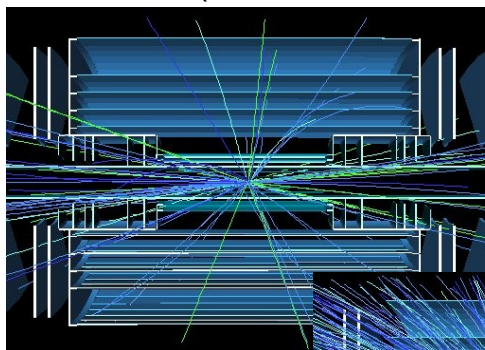
Phase 2 – 2022 → Upgrades for high-luminosity LHC



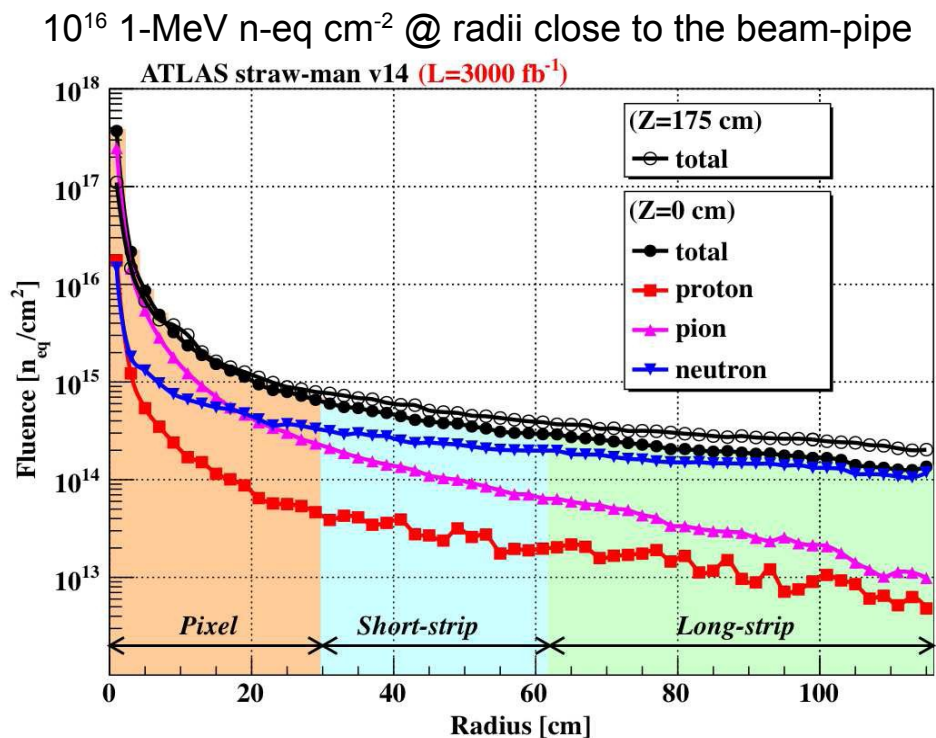
environment for new tracker at HL-LHC

- huge increase in particle multiplicities → fluence $\sim 200\times$ higher than at LHC
 - current tracker won't be able to stand cumulated radiation dose
- 200 pile-up events per bunch crossing (~ 23 at LHC design luminosity)
 - occupancy will be too high (i.e. TRT) → higher granularity needed

5 collisions ($0.2 \times 10^{34} \text{ cm}^{-2} \text{ s}^{-1}$)



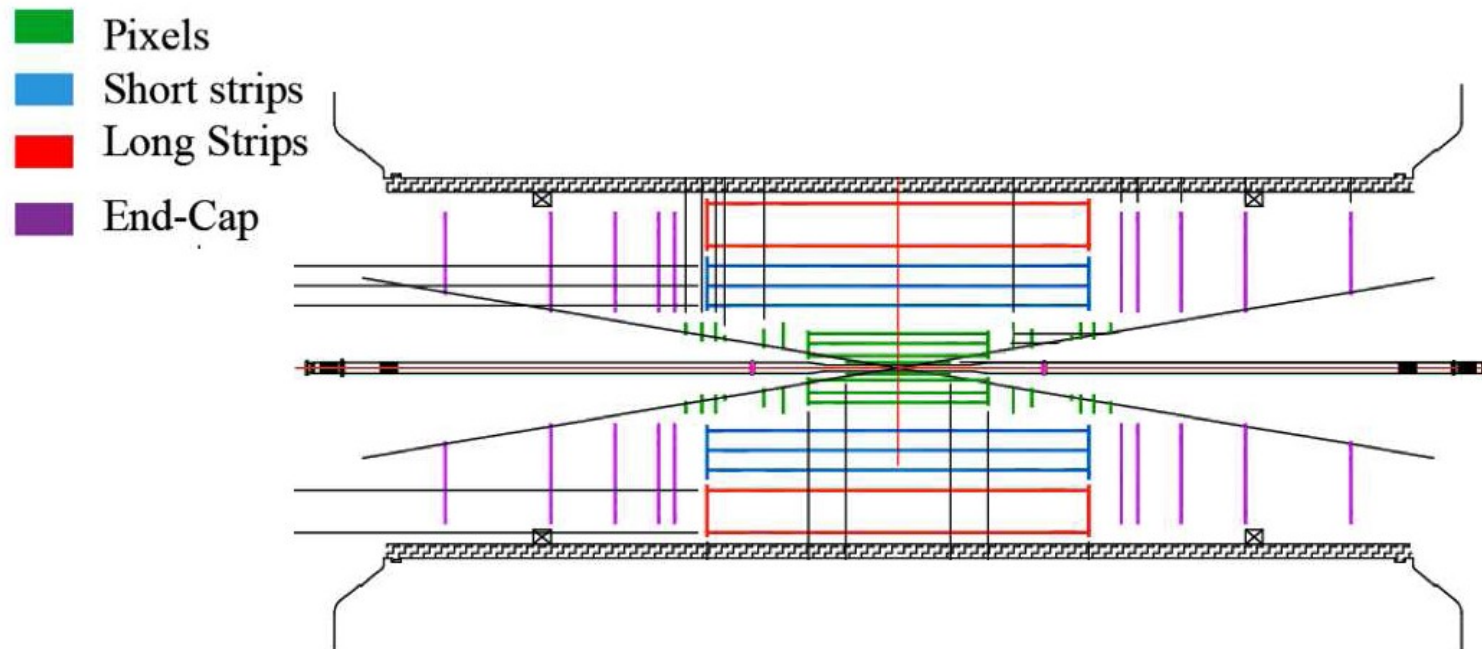
400 collisions ($10 \times 10^{34} \text{ cm}^{-2} \text{ s}^{-1}$)



How could a new Tracker look like?

ATLAS Tracker Upgrade: straw-man layout

- > whole Inner Detector is to be **replaced by an All-Silicon-Tracker** → no TRT
 - central barrel region: **4 pixel and 5 strip layers**
 - forward region: **6 pixel and 5 strip disks**
 - layout ensures 9-hit coverage in the pseudo-rapidity range $|\eta| < 2.5$



- > **new tracker will consist of $>100\text{m}^2$ of silicon**
e.g. Strip detector: channel number increased from 6M to $\sim 40\text{M}$ @HL-LHC

ATLAS Tracker Upgrade: specs & facts

> >100m² of silicon in total:

- channels in Strip Detector: 6M @LHC → ~40M @HL-LHC
- channels in Pixel Detector: 80M @LHC → ~500M @HL-LHC

> power consumption:

- Strip Detector: 22 kW @LHC → ~50 kW @HL-LHC
- Pixel Detector: 7 kW @LHC → ~30 kW @HL-LHC

> related issues / limiting factors:

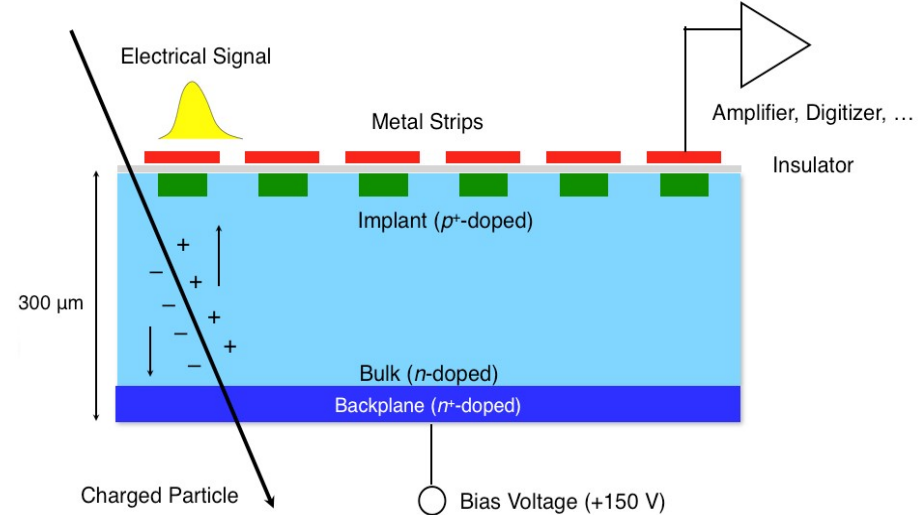
- How to get current needed to the electronics?
- More modules result in more cables for power, data and detector control signals
→ new powering schemes needed (DC-DC or Serial powering)
- Material Budget:
Can we build a better/lighter tracker?



Silicon strip sensors

> short reminder:

- passing ionizing particles create free charge carriers (e^-/h pairs) in depletion region / bulk
- charges drift to p & n doped side (bias voltage)
- usually one side is segmented (i.e. strips, pixels)
- signal at strip is amplified by charge sensitive amplifier ($100\text{-}10000e^- \rightarrow \sim 1\text{-}1000\text{mV}$)
- usually test charges can be directly injected into amplifier inputs for calibration & testing

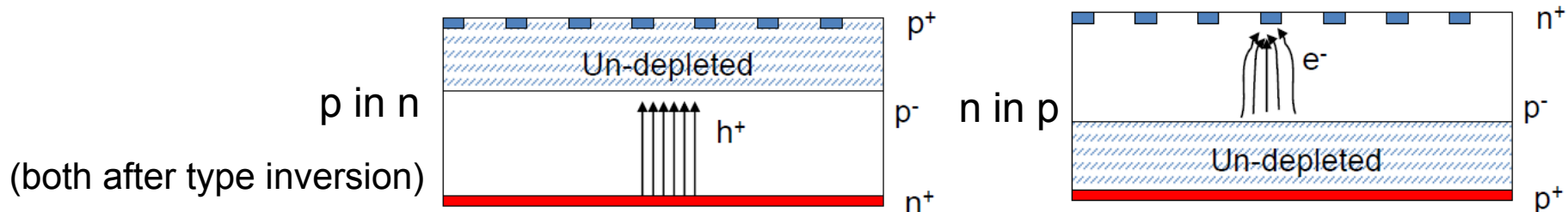


> current Strip Detector uses p-in-n Si-sensors

> advantages of n-in-p technology:

- electrons are collected \rightarrow higher mobility
- $\sim 33\%$ smaller trapping constant
- deposited charge can reach electrode even if sensor is under-depleted

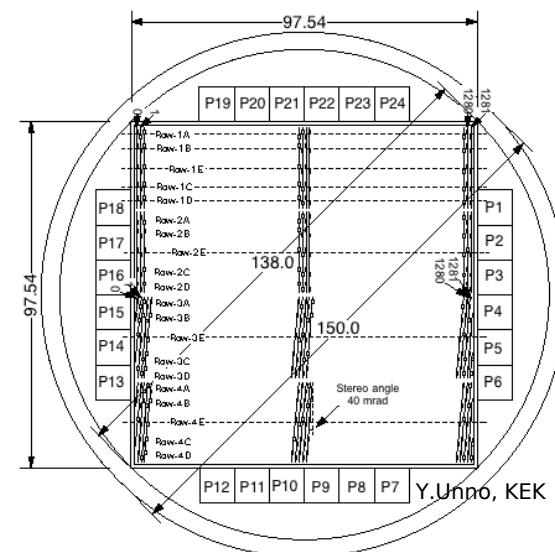
- typical thickness: $\sim 300\text{ }\mu\text{m}$
- energy loss of MIP per e/h pair:
 $\langle E \rangle = 3.6\text{ eV}$ (at 300°K), (gases: $20\text{-}40\text{ eV}$)
- total e^-/h pairs: ~ 25000
- drift times: $\sim 8\text{ ns } e^-$, 25 ns holes



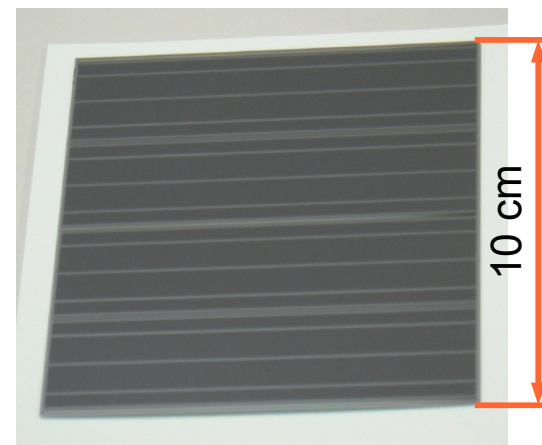
Barrel Sensor Prototypes

➤ sensor prototypes for SCT Barrel detector modules

- capacitively coupled, polysilicon biased n-in-p-type devices (produced by Hamamatsu)
- 4 rows of 1280 strips each
- 2 rows with tilted strips → stereo angle
- several thousand modules will be needed
- sensor specification have to be checked before module production



Axial-Stereo Sensor

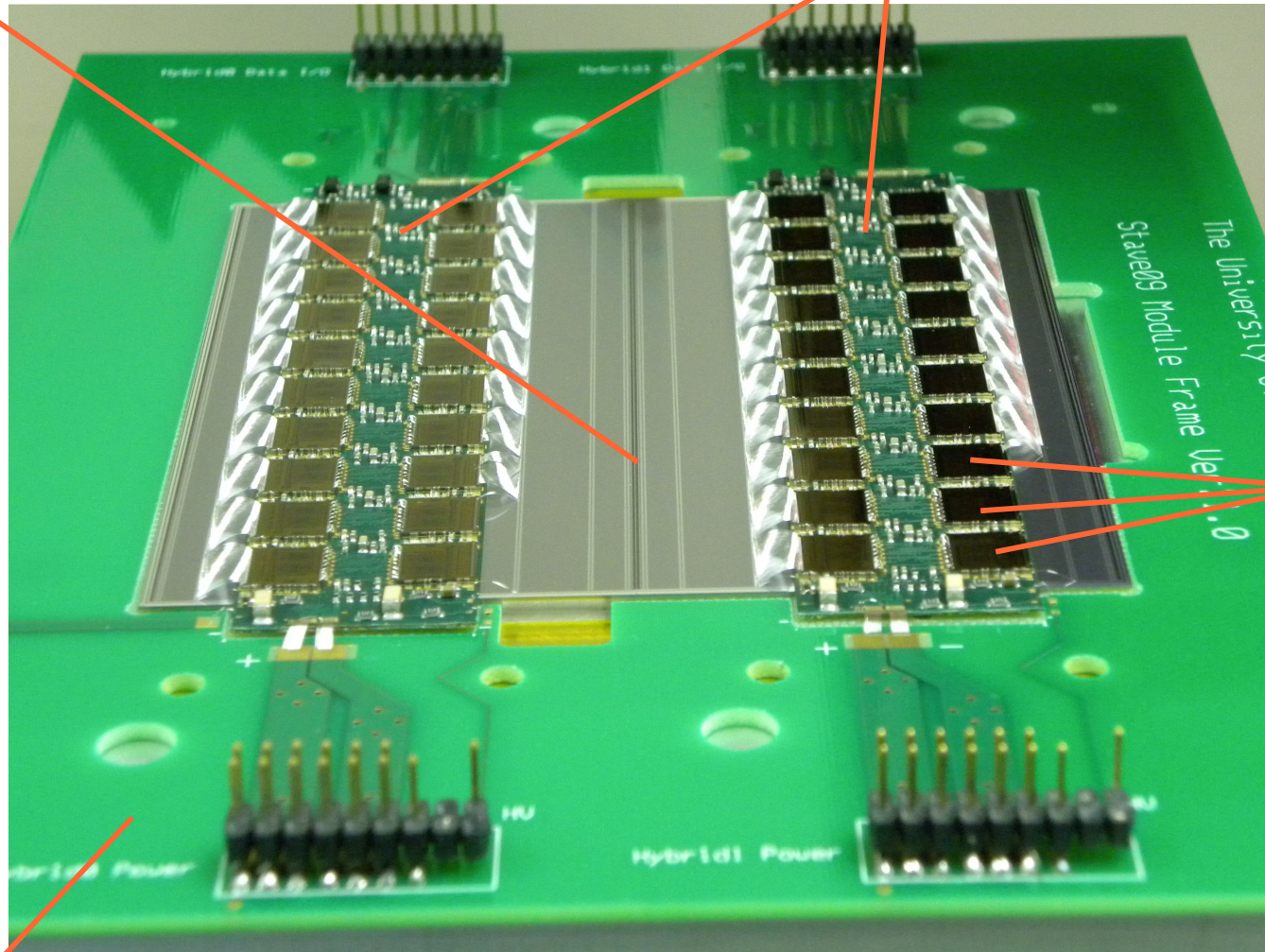


	ATLAS	ATLAS@SLHC
sensor size	6,4x6,4 cm ²	9,75x9,75 cm ²
type	p-in-n	n-in-p
# of strips	768	5120
pitch	80 μm	74,5 μm
length	12,6 cm	2,4 cm
max. V _{depl}	500 V	1000 V

Strip Detector Module (single sided version)

Sensor (4 rows of 1280 strips)

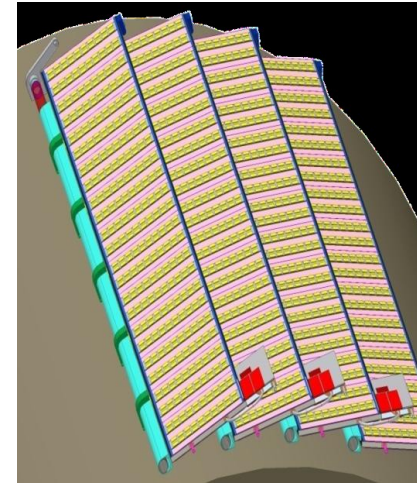
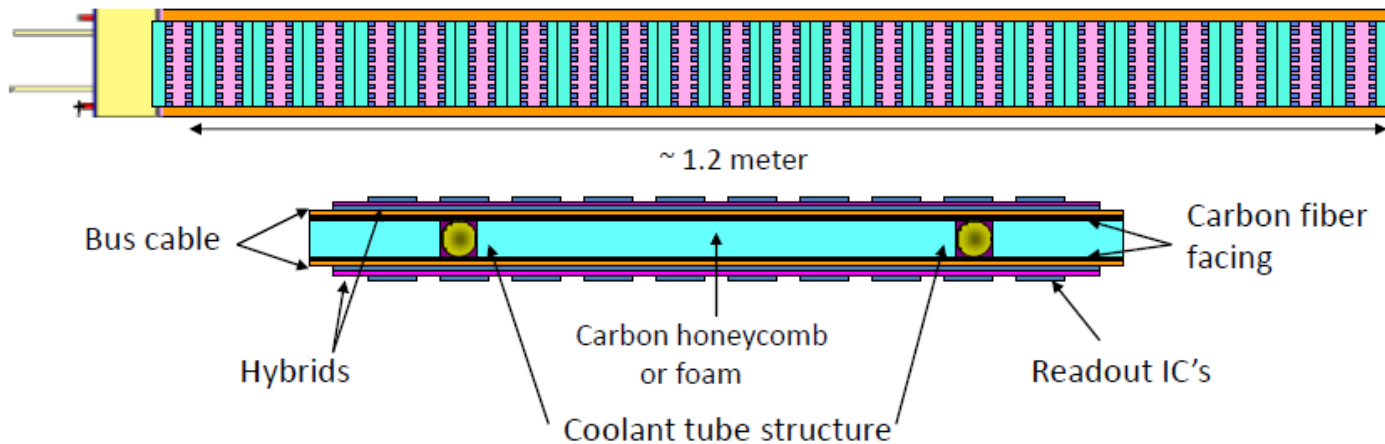
Hybrids



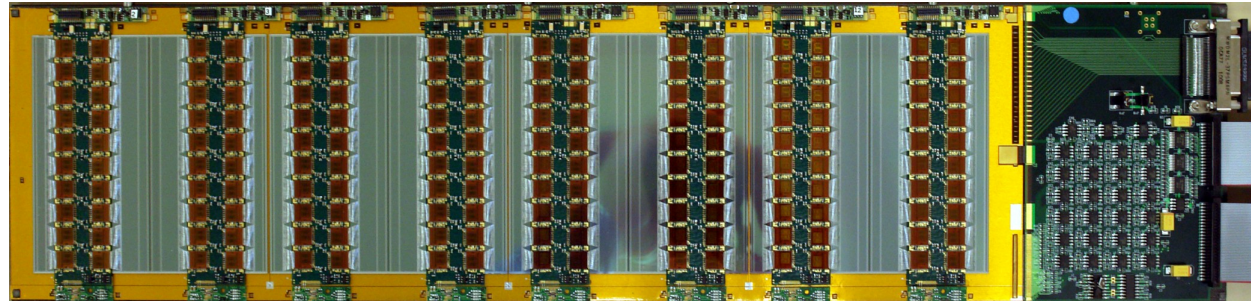
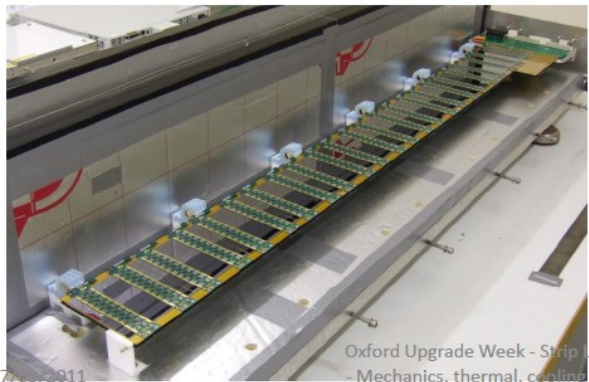
read-out chips
(128 channels)

testing frame

Integration concepts – Staves (baseline approach)

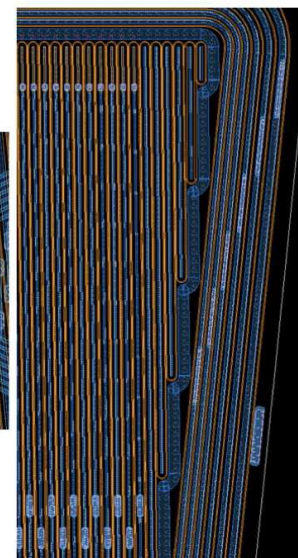
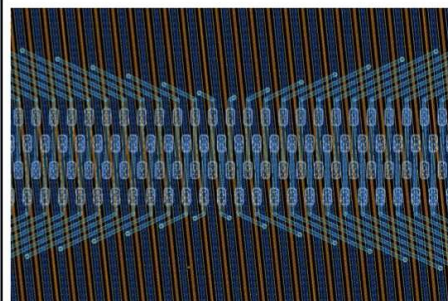
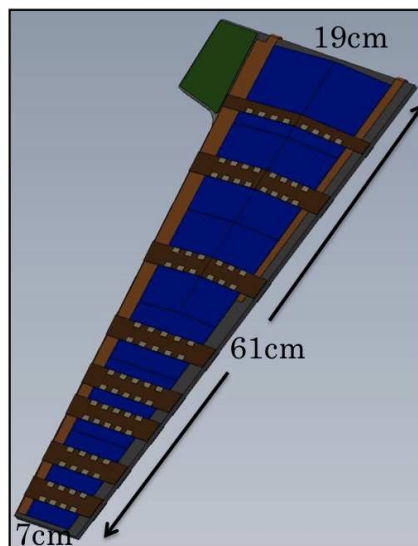
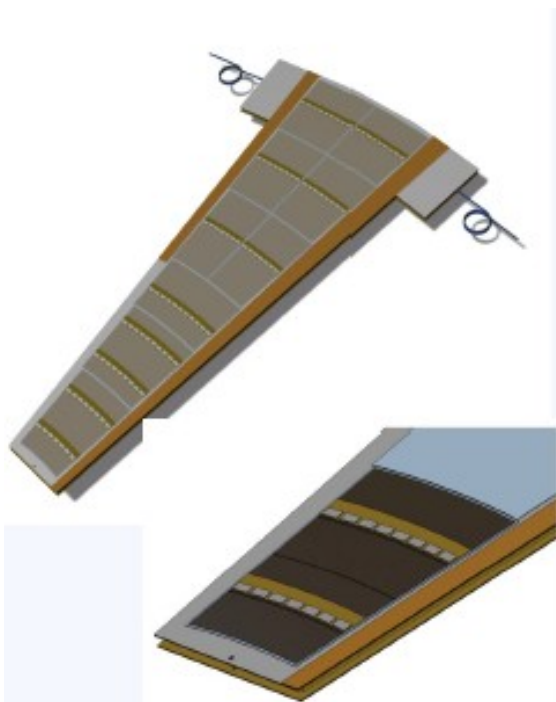
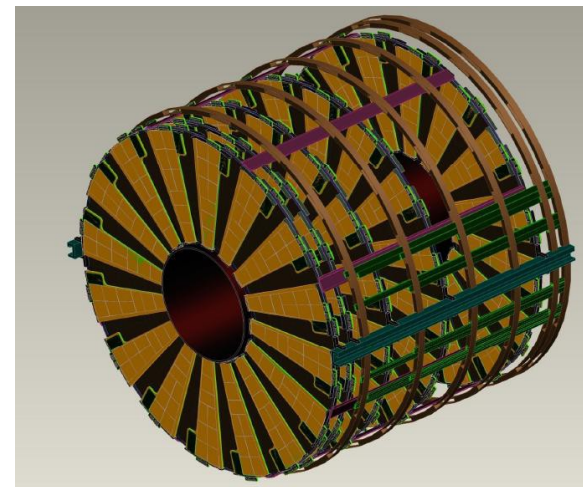


- Stave: 12 single-sided modules glued on common support & cooling structure from both sides



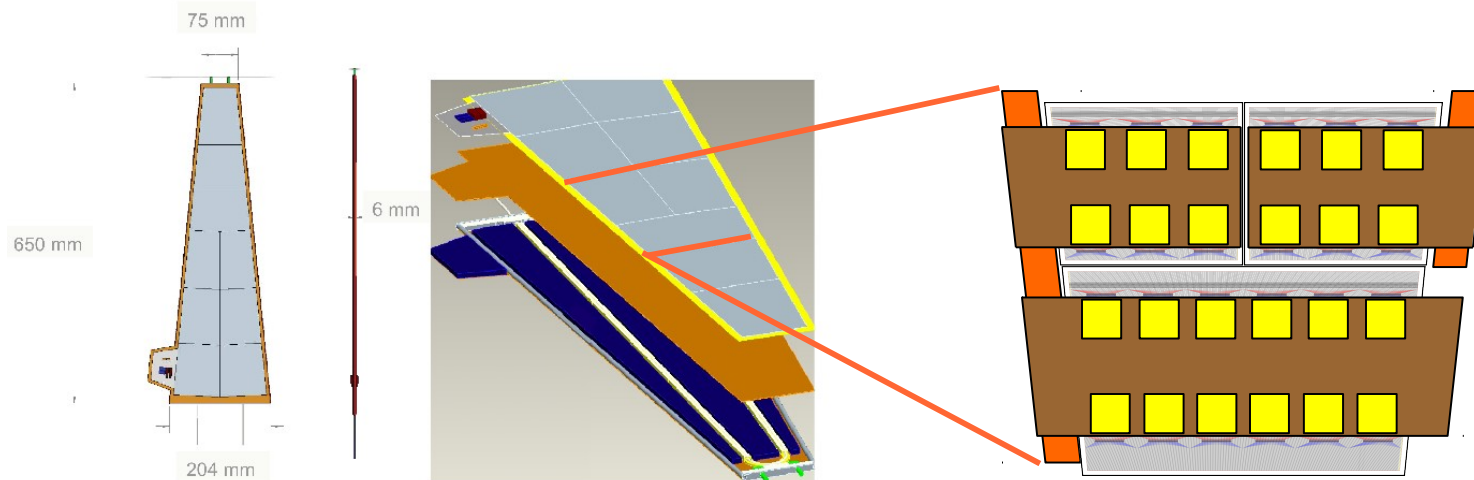
Integration concept - End-caps

- layout closely follows the barrel stave concept
 - 5 discs on each end-cap, 32 Petals per disc
 - common mechanical & thermal support: carbon honeycomb core with embedded cooling loop
- major difference from Barrel Stave:
 - 9 different sensor & 11 hybrid layouts
 - sensors with radial strips, non-uniform pitch



How are we involved?

- DESY: probable macro assembly site of one Silicon strip detector end-cap
- Prototype Phase → Petal14 project:
 - show feasibility by design & construction of a full size & fully functional Petal prototype
 - collaborators: HU Berlin, Uni Freiburg
 - @ Zeuthen: sensor testing, module production & testing
 - @ Hamburg: petal assembly, macro assembly & testing
- **step 0:** gain expertise in barrel module production & stave community (Stave09)
- **step 1:** design & construct miniature prototype → Petalet:



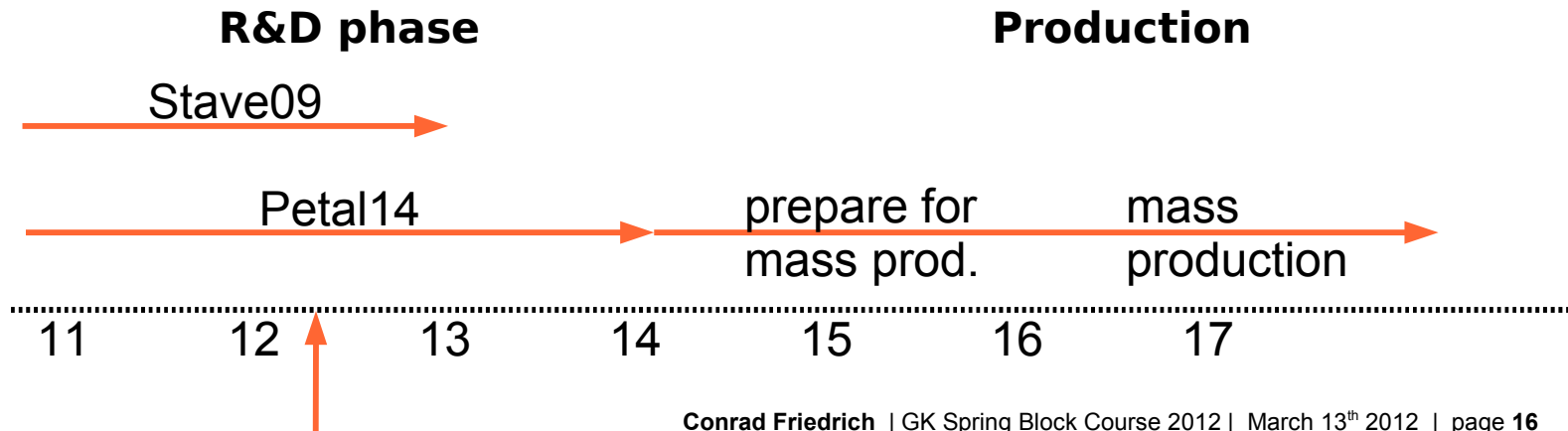
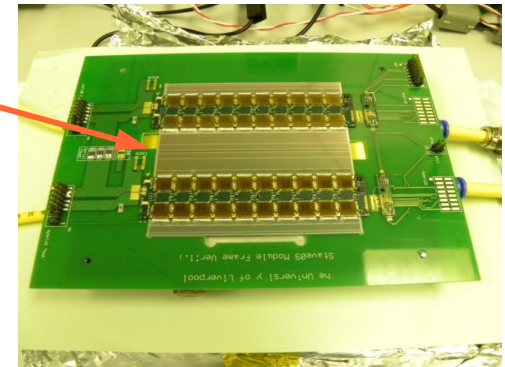
SCT Barrel Upgrade - Stave09 program

> goal: build a full size stave prototype (24 modules)

7 sites are coming on-line for hybrid/module assembly and testing → DESY

> barrel module production @ DESY

- assembly of modules for Stave09-Program
- to gain expertise in: sensor testing, tooling,
- mechanical module assembly (gluing / wire bonding),
- electrical testing of hybrids & modules (DAQ),
- tests of larger structures (Stavelets) → CERN



SCT Barrel Upgrade – Module Production



> ingredients:

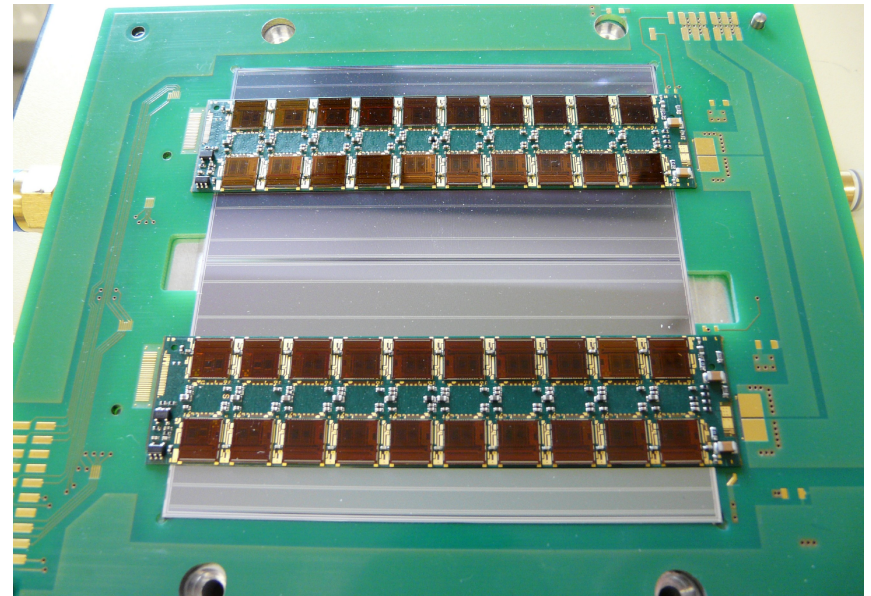
- 1 **Si strip sensor** ($10 \times 10 \text{ cm}^2$ n-in-p)
- 2 **hybrids** ($\sim 10 \times 2 \text{ cm}^2$ flexible PCB)
- 40 **read-out chips** ($\sim 1 \times 1 \text{ cm}^2$ ASICs)
- ~ 6.000 wire-bonds (25 μm thick Al)

1. hybrid assembly:

- 1.1 – glue read-out chips onto hybrids
- 1.2 – chip to hybrid wire bonding
- 1.3 – hybrid testing (electrical / DAQ)

2. final module assembly:

- 2.1 – glue hybrids on sensors
- 2.2 – chips to sensor wire bonding
- 2.3 – module testing (electrical / DAQ)

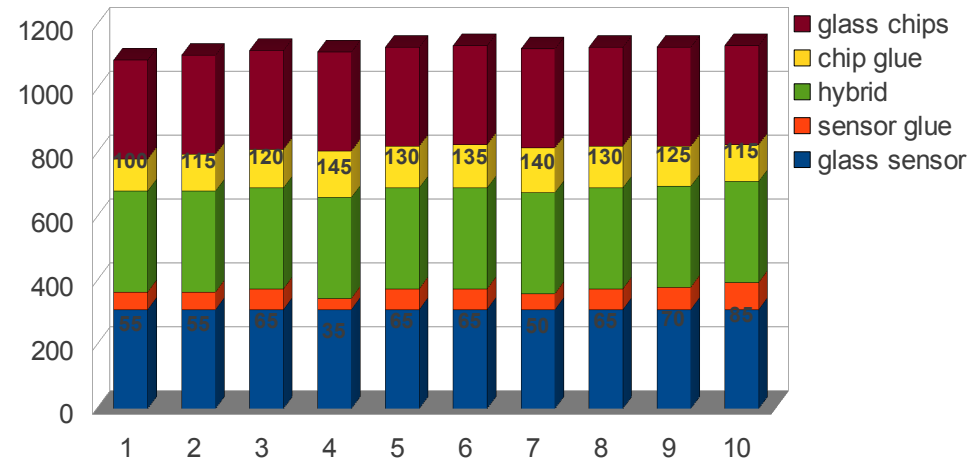


checking mechanical properties

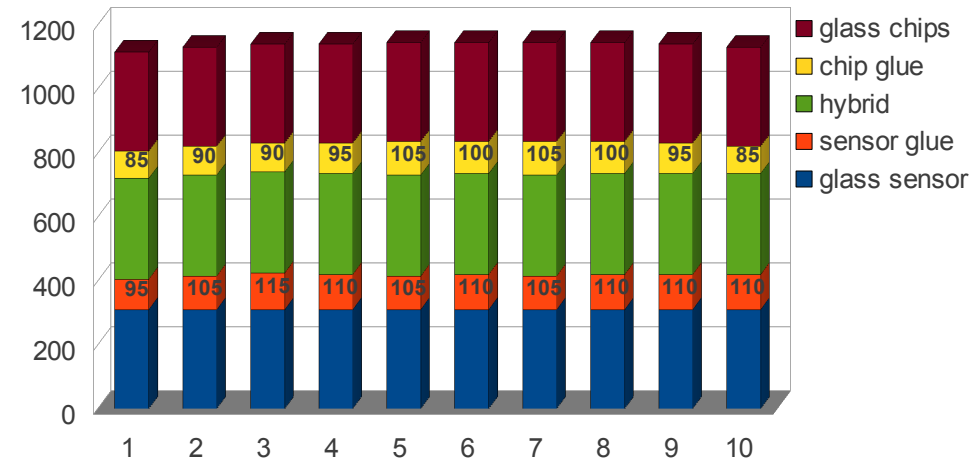
> gluing thickness of chips & hybrids in more detail



glue applied immediately



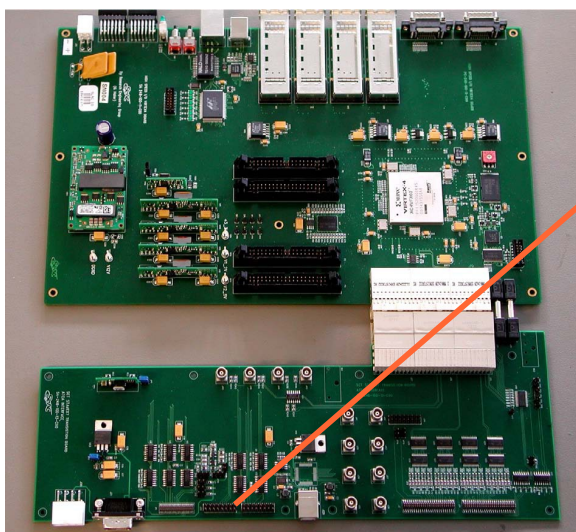
pre-curing time: 45 min



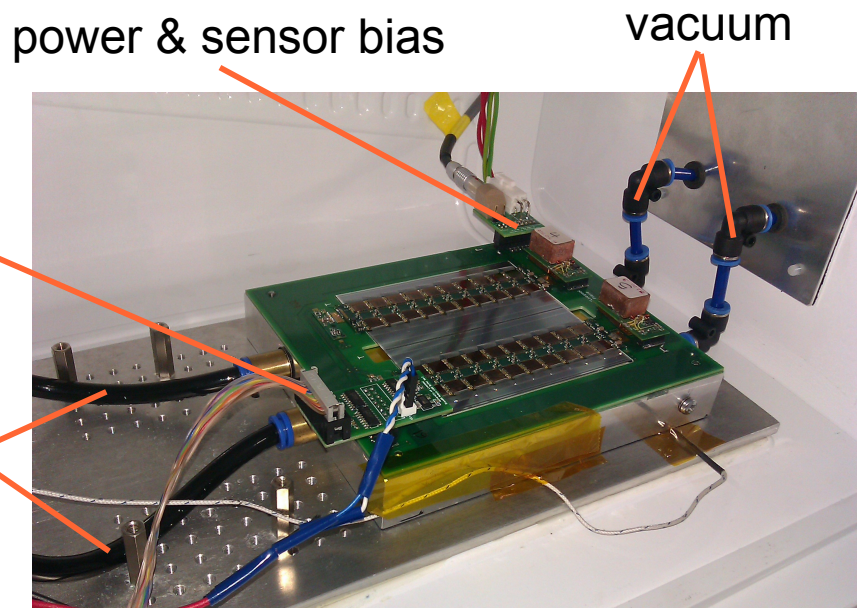
electrical testing / DAQ

➤ moved to new lab & installed infrastructure:

- vacuum system
- chiller for water cooling (down to -30°C)
- Nitrogen supply (for storage & to avoid condensation)
- power supplies, ...
- FPGA based read-out system (HSIO)
(for read-out of up to 24 modules)



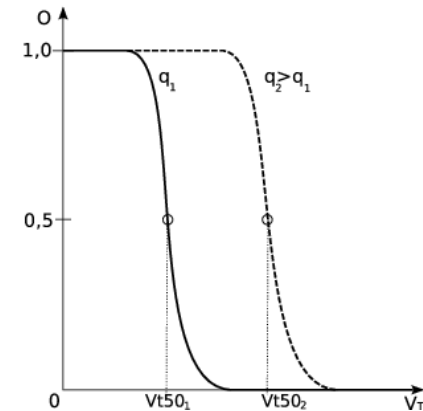
HSIO read-out system



read-out architecture & electrical tests

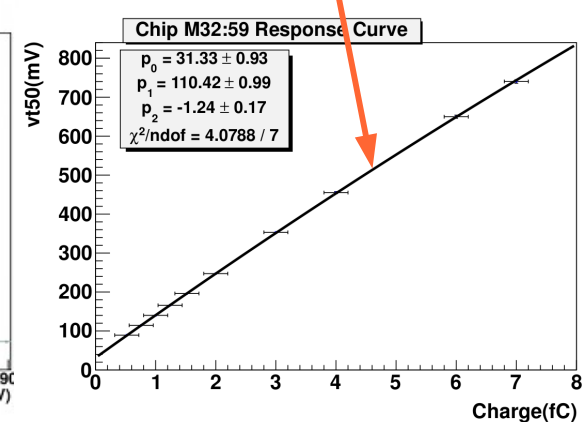
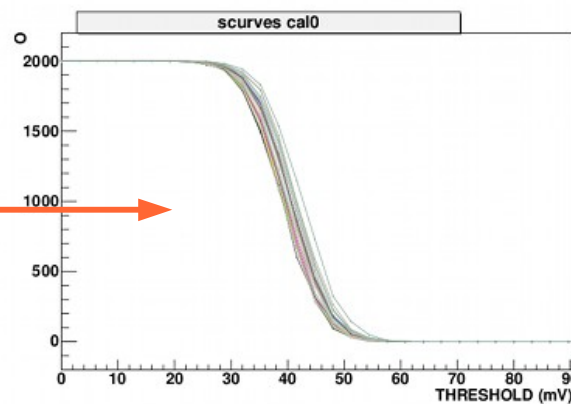
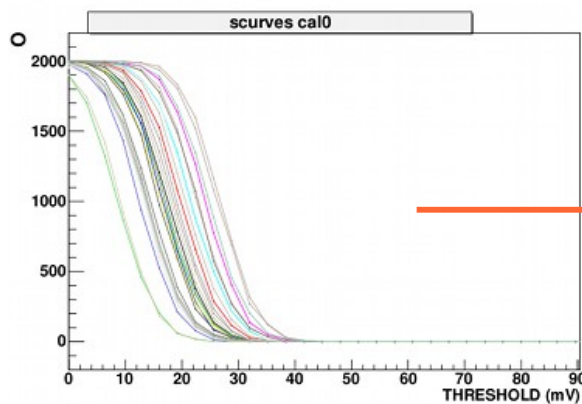
> Binary readout (digitization in the front-end electronics):

- amplification of signal (charge sensitive amplifier)
- discriminator compares signal with a threshold
returns 1 (hit), if signal at strip is above threshold
- hits & time-stamp buffered in FIFO & read-out if triggered



> response certain charge should be uniform across all channels

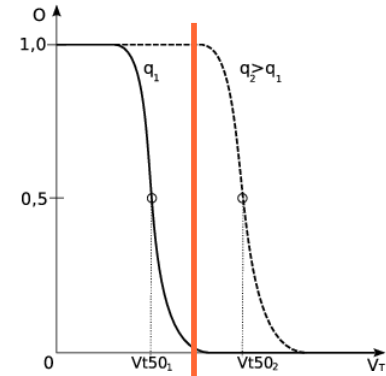
- self-injection of different charges & scan over threshold → response curve
- but amplifier response varies (manufacturing, supply voltage distribution, etc.)
→ **threshold calibration needed**



noise & noise occupancy

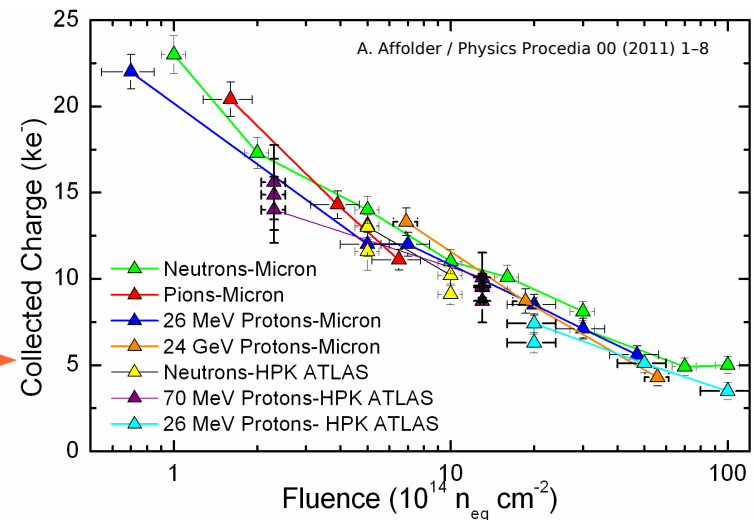
> several noise sources contribute to noise signal at output:

- noise current of biasing circuit
- shot noise from sensor leakage current
- noise sources within the amplifier itself (thermal, shot, low-freq. noise)



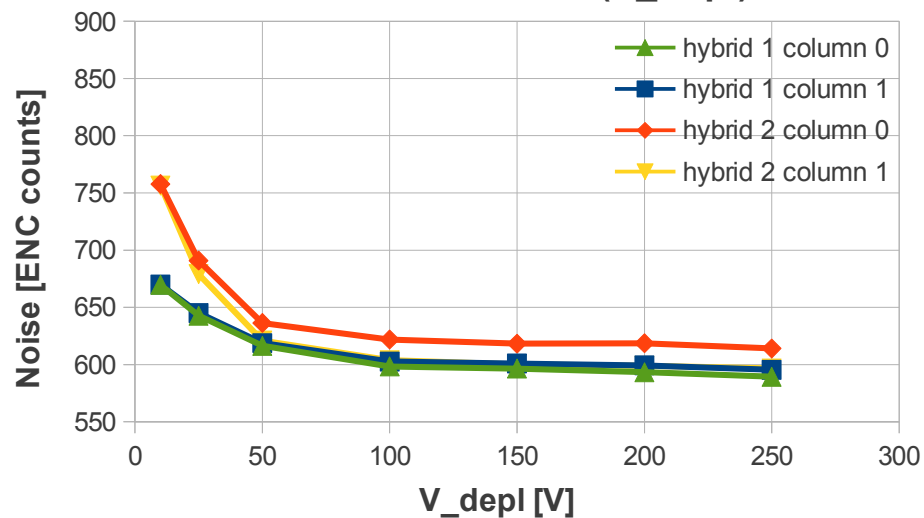
> output noise manifest as smeared out s-curves in threshold scan → fit

- noise usually denoted as corresponding (input) noise charge at amplifier input: equivalent noise charge (ENC)
- input noise typically at: ~ 600 ENC counts
- typical threshold setting: $1fC$ ($\sim 6200e$)
- charge deposited: ~ 25000 e/h pairs
→ theoretical S/N ratio up to 40:1! (unirradiated)
- but charge collection efficiency will drop

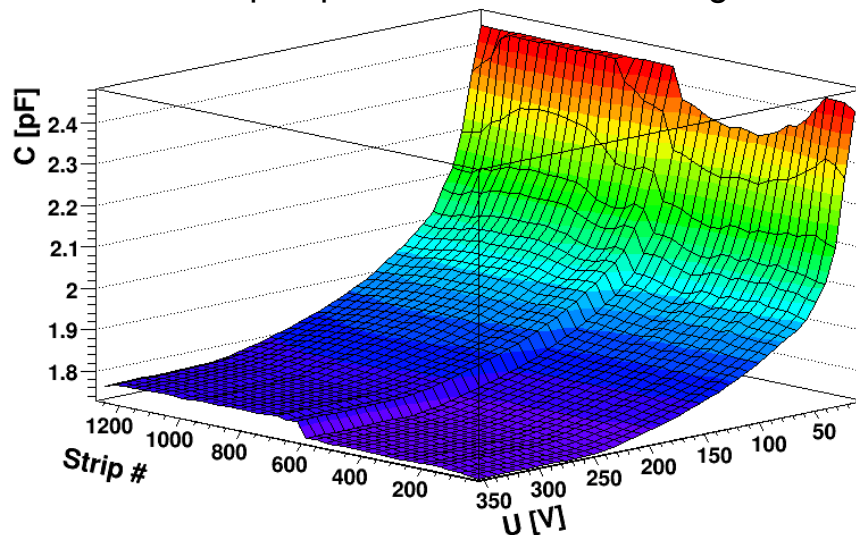


Noise dependence on depletion voltage

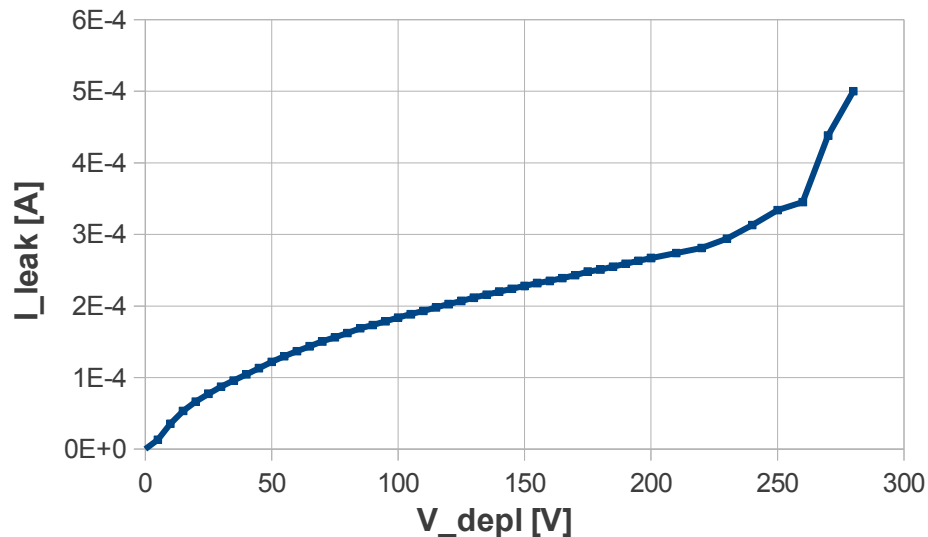
Stave module - Noise (V_{depl})



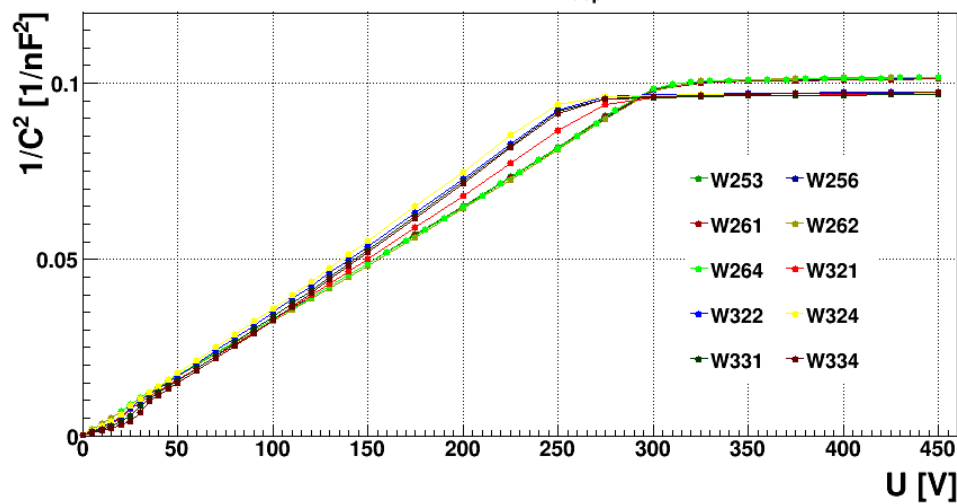
strip capacitance vs. bias voltage



Stave module - sensor IV-curve

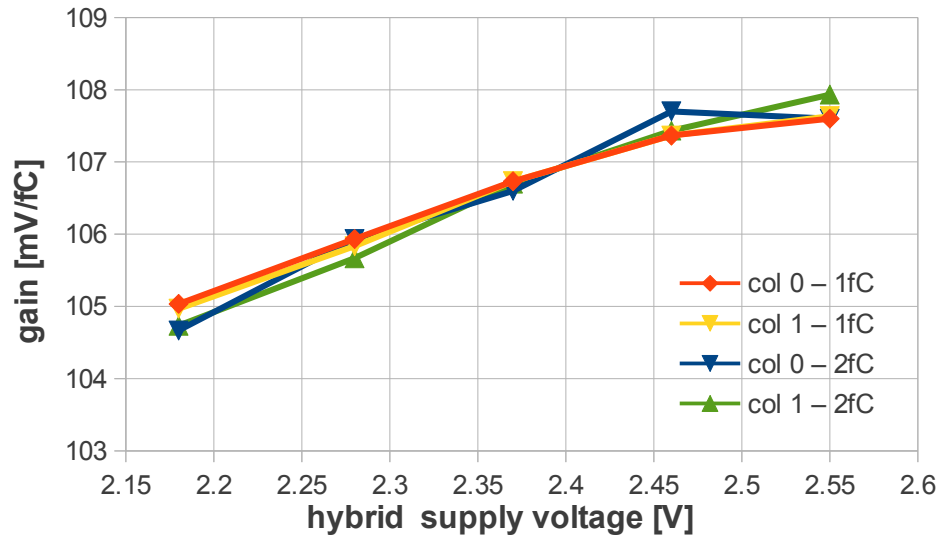


ATLAS07-Series3A CV-bulk $U_{\text{depl}}=0-450$ V $T=22$ C

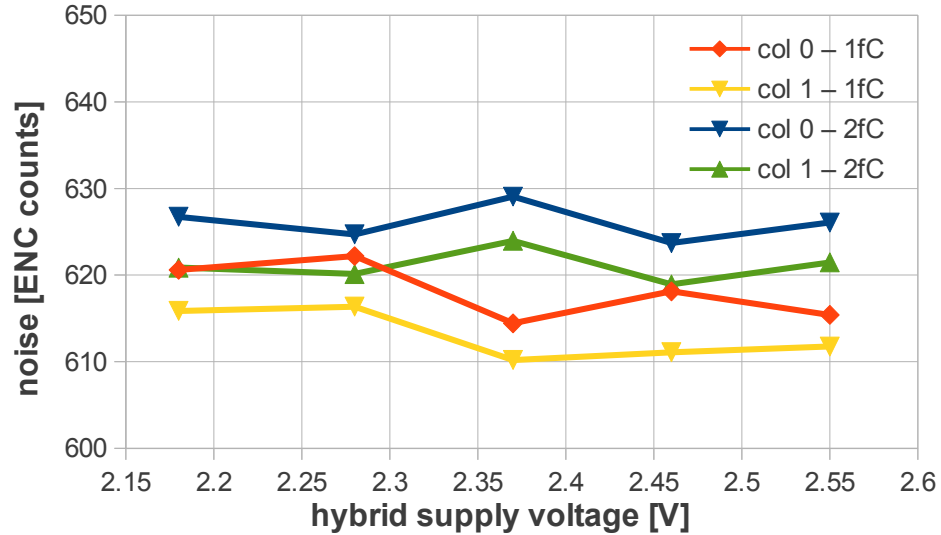


noise dependence on supply voltage & temperature

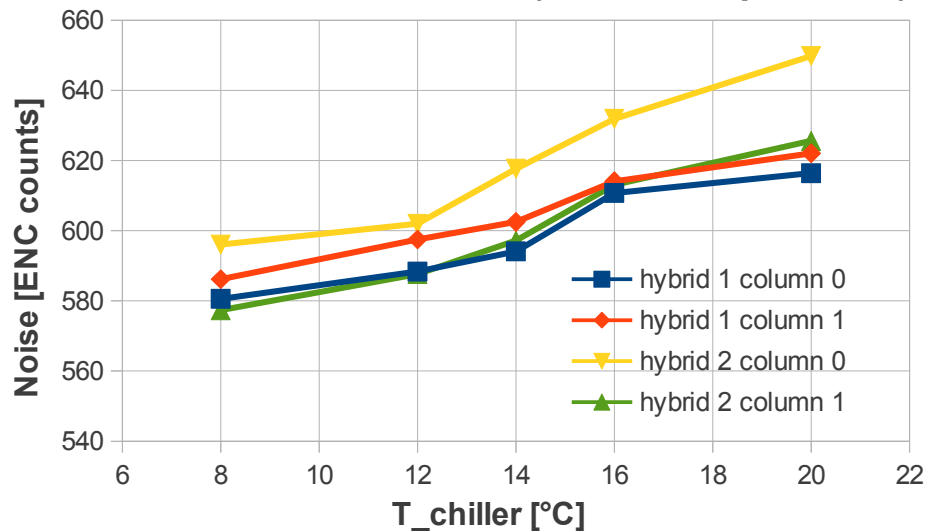
gain(supply voltage)



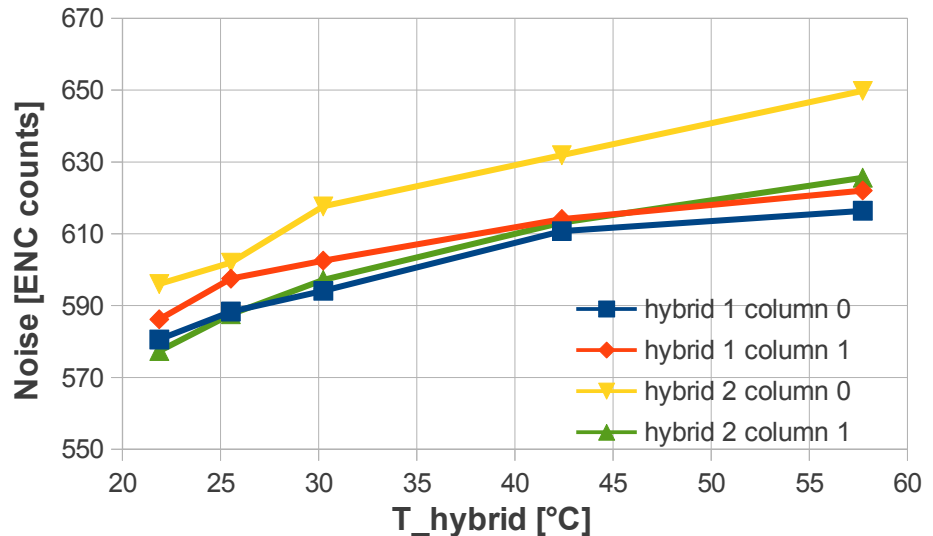
input noise(supply voltage)



Stave module - Noise (Chiller temperature)



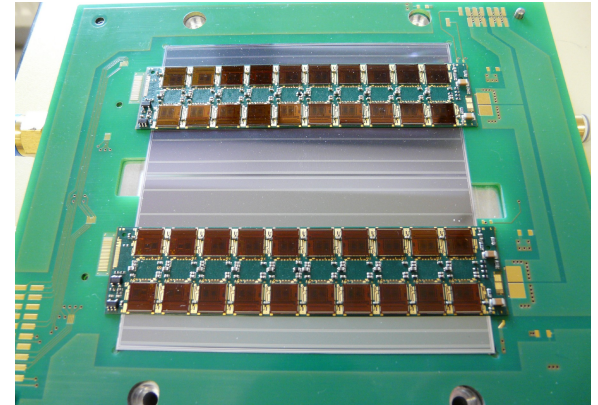
Stave module - Noise (hybrid temperature)



Summary

➤ current ATLAS Inner Detector will be replaced by an all-Silicon Tracker to account for:

- larger track densities & pile-up
- higher demands on radiation hardness
- limits in power consumption & cooling, services and material budget



➤ our current focus → ATLAS Strip Detector Upgrade:

- mechanical assembly of module prototypes (started with barrel modules)
- DAQ / electrical testing
- End-caps: design and construction of a Petal prototype in 2014
starting with miniature “Petalet” - first sensors to arrive in summer

➤ 10 years to go for Phase 2 Upgrades, but still very ambitious time-line

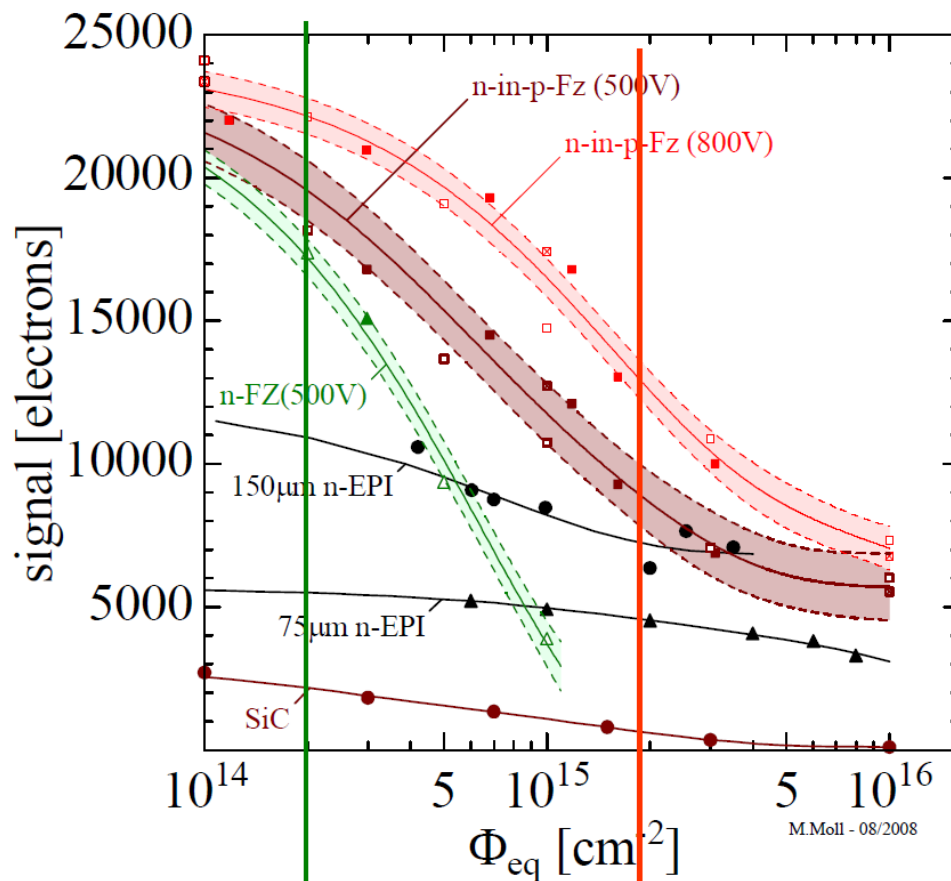
- start of mass production ~2016 (several 1000 modules have to be produced & tested)

backup slides



Backup 0: CCE

• Signal comparison for various Silicon sensors



Silicon Sensors

- p-in-n (EPI), 150 μm [7,8]
- ▲ p-in-n (EPI), 75μm [6]
- n-in-p (FZ), 300μm, 500V, 23GeV p [1]
- n-in-p (FZ), 300μm, 500V, neutrons [1]
- n-in-p (FZ), 300μm, 500V, 26MeV p [1]
- n-in-p (FZ), 300μm, 800V, 23GeV p [1]
- n-in-p (FZ), 300μm, 800V, neutrons [1]
- n-in-p (FZ), 300μm, 800V, 26MeV p [1]
- ▲ p-in-n (FZ), 300μm, 500V, 23GeV p [1]
- △ p-in-n (FZ), 300μm, 500V, neutrons [1]

Other materials

- SiC, n-type, 55 μm, 900V, neutrons [3]

References:

- [1] p/n-FZ, 300μm, (-30°C, 25ns), strip [Casse 2008]
- [2] p-FZ, 300μm, (-40°C, 25ns), strip [Mandic 2008]
- [3] n-SiC, 55μm, (2μs), pad [Moscatelli 2006]
- [4] pCVD Diamond, scaled to 500μm, 23 GeV p, strip [Adam et al. 2006, RD42]
- Note: Fluence normalized with damage factor for Silicon (0.62)
- [5] 3D, double sided, 250μm columns, 300μm substrate [Pennicard 2007]
- [6] n-EPI, 75μm, (-30°C, 25ns), pad [Kramberger 2006]
- [7] n-EPI, 150μm, (-30°C, 25ns), pad [Kramberger 2006]
- [8] n-EPI, 150μm, (-30°C, 25ns), strip [Messineo 2007]

Note: Measured partly under different conditions!
Lines to guide the eye (no modeling)!

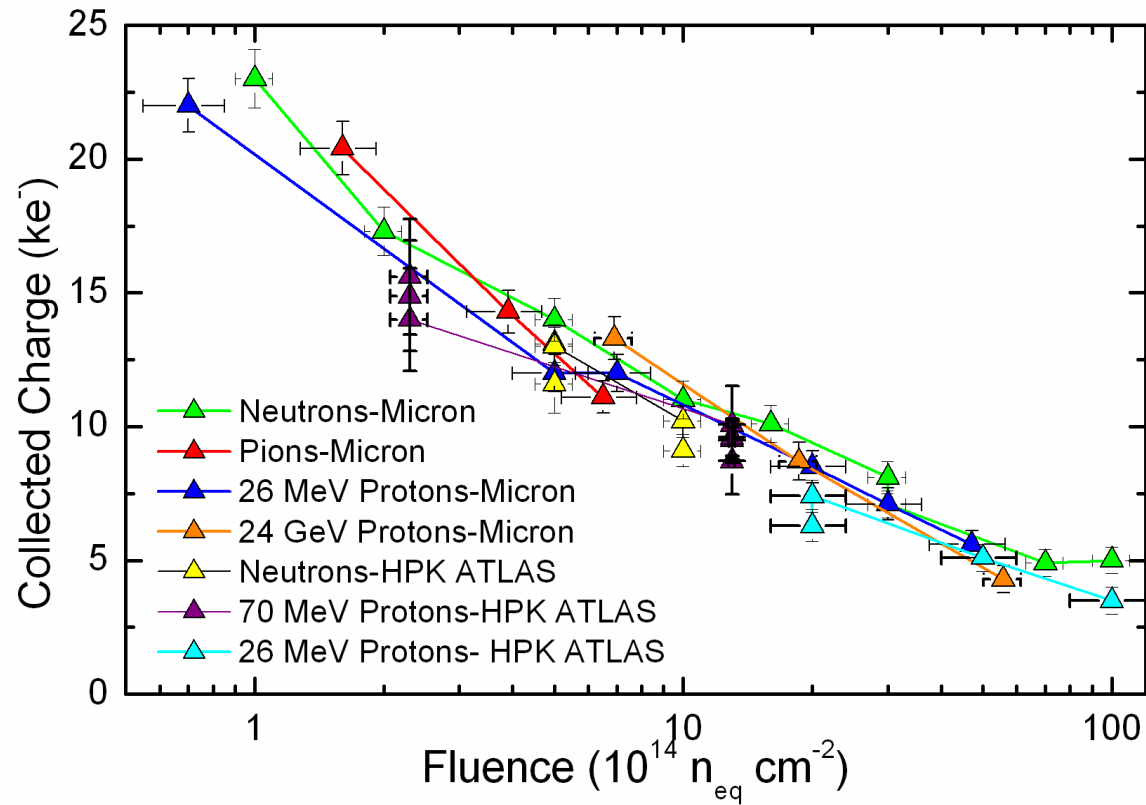
LHC

SLHC

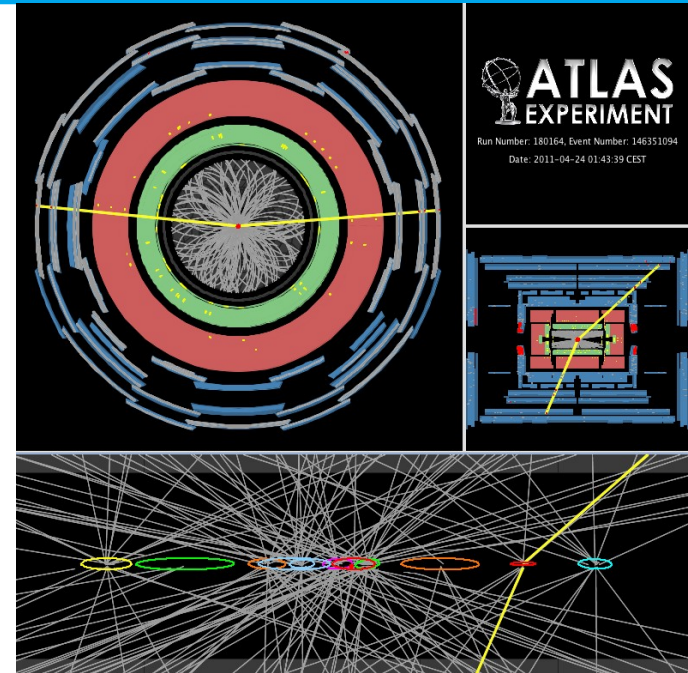
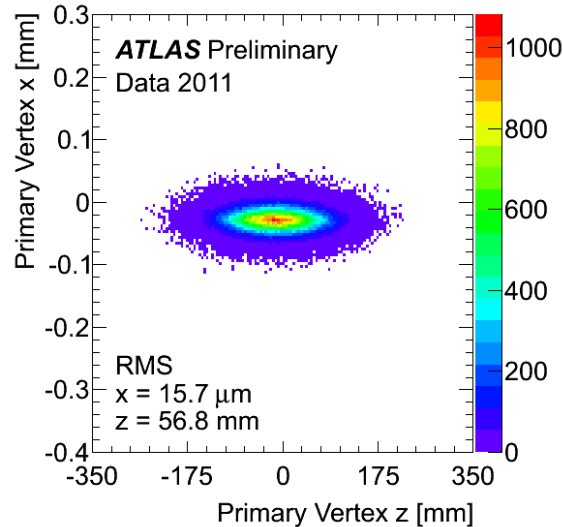
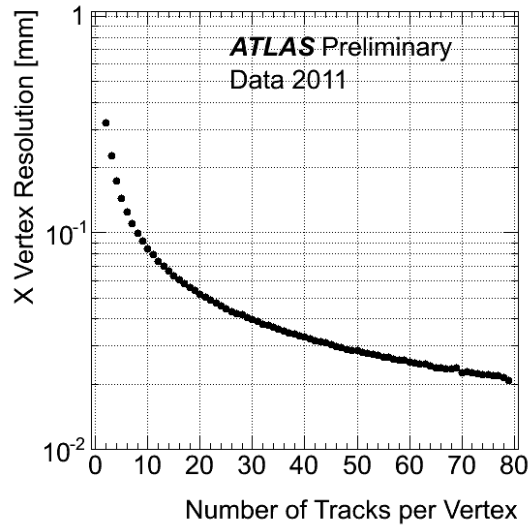
highest fluence for strip detectors in LHC: The used p-in-n technology is sufficient

n-in-p technology should be sufficient for Super-LHC at radii presently (LHC) occupied by strip sensors

Backup 1: CCE2



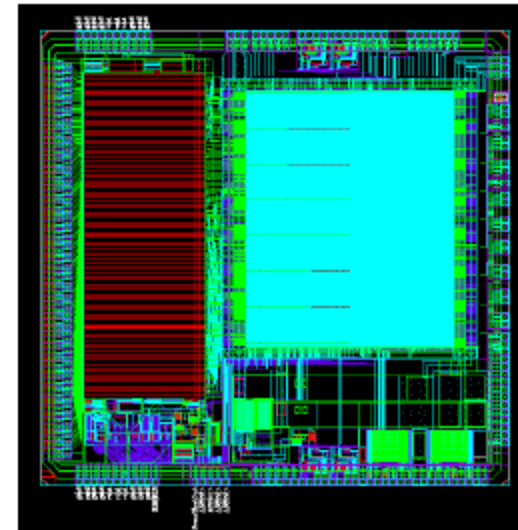
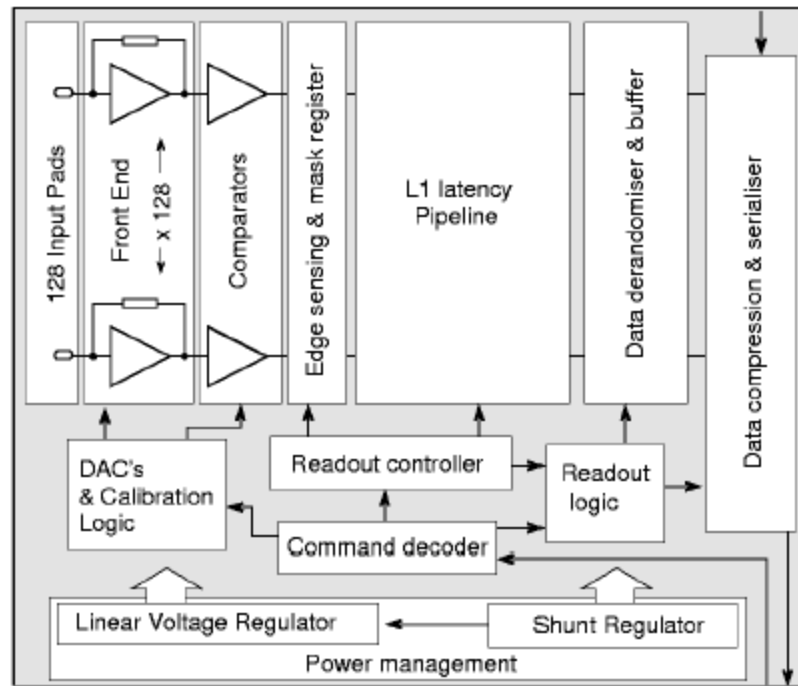
Backup 1: current resolution



current detector sizes & resolution

Subdetector	r (cm)	Elements size	Resolution (X * Y)	hits/track (average)	channels
Pixel (silicon pads)	5 – 12.5	50 μ m * 400 μ m	10 μ m * 115 μ m	3	80 x 10 ⁶
SCT (silicon microstrips)	30 – 52	80 μ m * 12 cm (stereo)	17 μ m * 580 μ m	8	6.3 x 10 ⁶
TRT (Transition Radiation)	56 – 107	4 mm (diameter)	130 μ m	30	3.5 x 10 ⁵

backup: ABCN-25



7.7 x 7.5 mm²

128 channels

35mA @ 2.0V Analogue

135mA @ 2.5V Digital

Backup: Trigger Upgrades

> **goal: preserve sensitivity to physics signatures**

- use finer granularity and depth calorimeter information
- learn from shower shape algorithms used at L2
- match information from different detectors (improve electrons/muons with ID tracks)
- build topological triggers (opening angles, invariant masses, etc.)

> **Track Trigger:**

> **Self-seeded Standalone Approach (CMS Baseline)**

- dedicated tracker layers select hits from high pT tracks
- read out only those hits to form tracks.

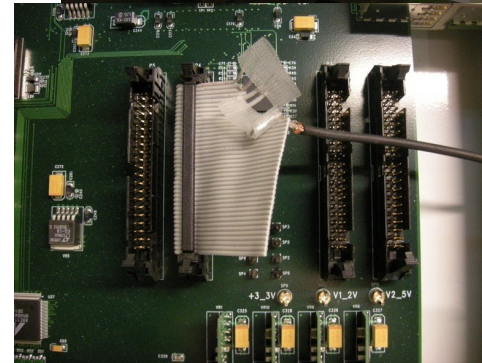
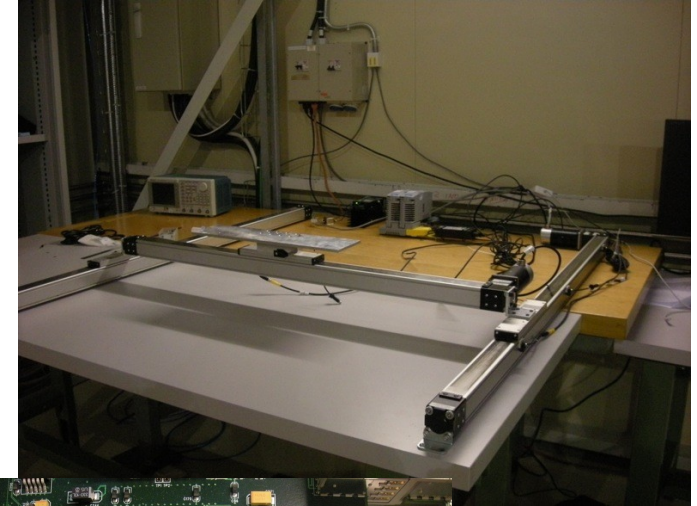
> **Regional Readout L0+L1 Approach**

- regional readout seeded by L1Calo or L1Muon information (small fraction of ID)
- may involve a two-stage L1 Trigger (L0 + L1) if the ID readout is not fast enough (may allow slower detectors to contribute also e.g. MDTs)
- seeds useful for other detectors to refine processing (calo/muon)

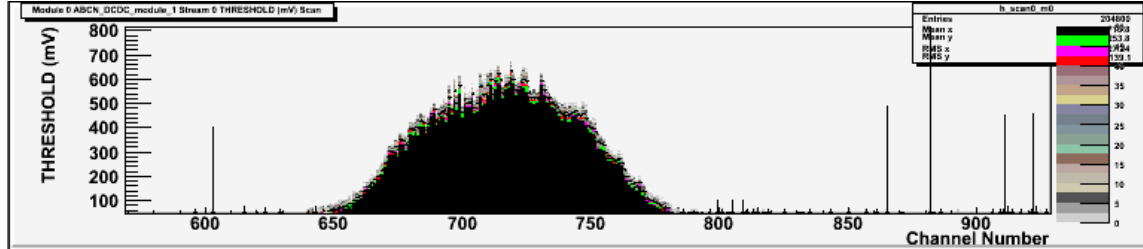
> **many simulations & performance studies in progress**

backup: laser test system

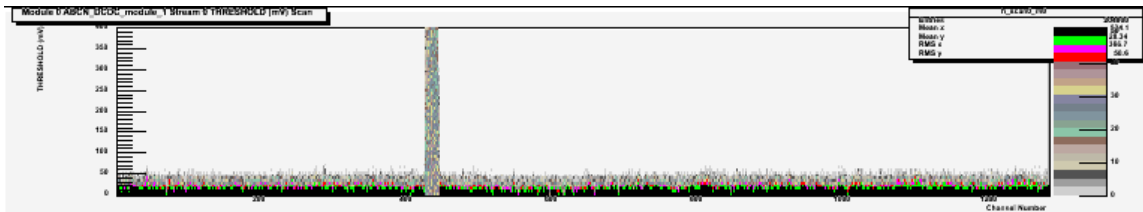
- laser triggered by L1A signal from HSIO
- charge injected into individual strips
- read-out - scanning through all channels
- status:
 - C++ software for motion control written & tested
 - design of base plate & dark box @ Freiburg
 - mountings for laser optics (collimator, lens, fibers) in production at CERN
 - measured focal width of laser
 - adjusted timings / delays for correct timing of read-out and tuned pulse shape for laser amp
- todo:
 - integrate motion & laser control into DAQ software & finish mechanical setup
 - measure final motion precision & repeatability: we need $< 20\mu\text{m}/\text{step}$ to hit in between strips



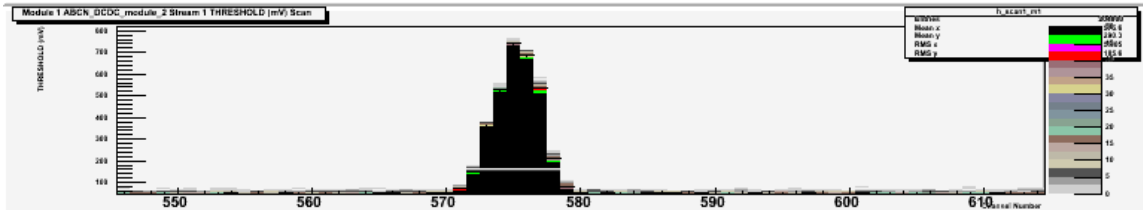
backup: laser focusing



no collimator & lens



setup 1 - continuous operation → width ~20strips



setup 2 – pulsed operation → width ~1-3 strips

→ focal width < 1 strip feasible with precise mountings
(& proper adjustment of laser output power and threshold)

